# NSN 5962-01-152-0903

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View Online at https://aerobasegroup.com/nsn/5962-01-152-0903

## **Body Length:**

Between 1.236 inches and 1.290 inches

## Body Width:

0.560 inches

## **Body Height:**

Between 0.130 inches and 0.170 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Hermetically sealed and burn in and programmed and 3-state output and bipolar

### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

Transistor-transistor logic

### Input Circuit Pattern:

11 input

## **Current Rating Per Characteristic:**

185.00 milliamperes reverse current, dc absolute

## **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

7.0 volts power source

### **Capitance Rating Per Characteristic:**

5.00 input picofarads and 8.00 output picofarads

### Time Rating Per Chacteristic:

90.00 nanoseconds access

#### Memory Device Type:

Prom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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